

# Sheng-chi Chen

## List of Publications by Year in descending order

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Version: 2024-02-01

23  
papers

300  
citations

1040056

9  
h-index

888059

17  
g-index

23  
all docs

23  
docs citations

23  
times ranked

444  
citing authors

#	ARTICLE	IF	CITATIONS
1	A study into enhanced oxidation resistance and its mechanism in Cr <sub>1-x</sub> Al <sub>x</sub> N/CrN/Cr multilayer films deposited on 9% Cr heat-resistant steel. <i>Ceramics International</i> , 2021, 47, 19134-19141.	4.8	5
2	In-Sn-Zn Oxide Nanocomposite Films with Enhanced Electrical Properties Deposited by High-Power Impulse Magnetron Sputtering. <i>Nanomaterials</i> , 2021, 11, 2016.	4.1	4
3	Multi-Ferroic Properties on BiFeO <sub>3</sub> /BaTiO <sub>3</sub> Multi-Layer Thin-Film Structures with the Strong Magneto-Electric Effect for the Application of Magneto-Electric Devices. <i>Coatings</i> , 2021, 11, 66.	2.6	8
4	Optoelectronic properties of p-type NiO films deposited by direct current magnetron sputtering versus high power impulse magnetron sputtering. <i>Applied Surface Science</i> , 2020, 508, 145106.	6.1	30
5	Transparent Conductive p-Type Cuprous Oxide Films in Vis-NIR Region Prepared by Ion-Beam Assisted DC Reactive Sputtering. <i>Coatings</i> , 2020, 10, 473.	2.6	9
6	The Optoelectronic Properties of p-Type Cr-Deficient Cu[Cr <sub>0.95-x</sub> Mg <sub>0.05</sub> ]O <sub>2</sub> Films Deposited by Reactive Magnetron Sputtering. <i>Materials</i> , 2020, 13, 2376.	2.9	6
7	Influence of Sputtering Power on the Electrical Properties of In-Sn-Zn Oxide Thin Films Deposited by High Power Impulse Magnetron Sputtering. <i>Coatings</i> , 2019, 9, 715.	2.6	6
8	Synthesis and characterization of n-type NiO:Al thin films for fabrication of p-n NiO homojunctions. <i>Journal Physics D: Applied Physics</i> , 2018, 51, 105109.	2.8	13
9	Impact of active layer thickness of nitrogen-doped In <sub>0.5</sub> Sn <sub>0.5</sub> Zn <sub>0.5</sub> O films on materials and thin film transistor performances. <i>Journal Physics D: Applied Physics</i> , 2018, 51, 175101.	2.8	13
10	p-type conductive NiOx: Cu thin films with high carrier mobility deposited by ion beam assisted deposition. <i>Ceramics International</i> , 2018, 44, 3291-3296.	4.8	18
11	Perovskite Solar Cells: Carbon Nanodot Additives Realize High-Performance Air-Stable p-i-n Perovskite Solar Cells Providing Efficiencies of up to 20.2% ( <i>Adv. Energy Mater.</i> 34/2018). <i>Advanced Energy Materials</i> , 2018, 8, 1870147.	19.5	3
12	Carbon Nanodot Additives Realize High-Performance Air-Stable p-i-n Perovskite Solar Cells Providing Efficiencies of up to 20.2%. <i>Advanced Energy Materials</i> , 2018, 8, 1802323.	19.5	86
13	The Influence of Oxygen Flow Ratio on the Optoelectronic Properties of p-Type Ni <sub>1-x</sub> O Films Deposited by Ion Beam Assisted Sputtering. <i>Coatings</i> , 2018, 8, 168.	2.6	12
14	Electrolytic Migration of Ag-Pd Alloy Wires with Various Pd Contents. <i>Journal of Electronic Materials</i> , 2018, 47, 3634-3638.	2.2	5
15	Growth Direction Control of ZnO Nanorods on the Edge of Patterned Indium-Tin Oxide/Aluminum-Doped Zinc Oxide Bilayers. <i>Crystal Growth and Design</i> , 2017, 17, 3100-3106.	3.0	2
16	Microstructures and optoelectronic properties of nickel oxide films deposited by reactive magnetron sputtering at various working pressures of pure oxygen environment. <i>Ceramics International</i> , 2017, 43, S369-S375.	4.8	30
17	Ag composition gradient CuCr <sub>0.93</sub> Mg <sub>0.07</sub> O <sub>2</sub> /Ag/CuCr <sub>0.93</sub> Mg <sub>0.07</sub> O <sub>2</sub> coatings with improved p-type optoelectronic performances. <i>Journal of Materials Science</i> , 2017, 52, 11537-11546.	3.7	14
18	Absorption Amelioration of Amorphous Si Film by Introducing Metal Silicide Nanoparticles. <i>Nanoscale Research Letters</i> , 2017, 12, 224.	5.7	5

#	ARTICLE	IF	CITATIONS
19	Optoelectronic Properties and the Electrical Stability of Ga-Doped ZnO Thin Films Prepared via Radio Frequency Sputtering. <i>Materials</i> , 2016, 9, 987.	2.9	14
20	Low-Temperature Bonding of Bi <sub>0.5</sub> Sb <sub>1.5</sub> Te <sub>3</sub> Thermoelectric Material with Cu Electrodes Using a Thin-Film In Interlayer. <i>Metallurgical and Materials Transactions A: Physical Metallurgy and Materials Science</i> , 2016, 47, 4767-4776.	2.2	5
21	Effect of Underlayer Structures on Microstructures and Magnetic Properties of Co-Rich Co-Pt Films Prepared at Ambient Temperature. <i>IEEE Transactions on Magnetics</i> , 2014, 50, 1-4.	2.1	1
22	NiGe Thin Films for Write-Once Blue Laser Media. <i>IEEE Transactions on Magnetics</i> , 2014, 50, 1-4.	2.1	2
23	Crystallization mechanisms and recording characteristics of Si/CuSi bilayer for write-once blu-ray disc. <i>Applied Physics Letters</i> , 2011, 99, .	3.3	9